	Application No.	Applicant(s)
₹.	00/000 050	WANAZAKI ET AL
Notice of Allowability	09/686,653 Examiner	YAMAZAKI ET AL.  Art Unit
· · ·	Lamino	Actions
	Toan Ton	2871
The MAILING DATE of this communication appear All claims being allowable, PROSECUTION ON THE MERITS IS herewith (or previously mailed), a Notice of Allowance (PTOL-85) NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT R of the Office or upon petition by the applicant. See 37 CFR 1.313	(OR REMAINS) CLOSED in this ap or other appropriate communication IGHTS. This application is subject t	plication. If not included not will be mailed in due course. THIS
1. This communication is responsive to papers filed 01/28/05		
2. The allowed claim(s) is/are <u>1,3-7,9-13,15-19,26-28,34,39,4</u>	10,43,46-52 and 55-60.	
3. ☑ The drawings filed on 10 October 2000 are accepted by the Examiner.		
4.  Acknowledgment is made of a claim for foreign priority una    a)  All b)  Some* c)  None of the:  1.  Certified copies of the priority documents have    2.  Certified copies of the priority documents have    3.  Copies of the certified copies of the priority do    International Bureau (PCT Rule 17.2(a)).	e been received. e been received in Application No. <u>0</u>	
* Certified copies not received:		
Applicant has THREE MONTHS FROM THE "MAILING DATE" noted below. Failure to timely comply will result in ABANDONN THIS THREE-MONTH PERIOD IS NOT EXTENDABLE.		complying with the requirements
5. A SUBSTITUTE OATH OR DECLARATION must be subminFORMAL PATENT APPLICATION (PTO-152) which give	uitted. Note the attached EXAMINER reason(s) why the oath or declara	R'S AMENDMENT or NOTICE OF ation is deficient.
6. CORRECTED DRAWINGS ( as "replacement sheets") must	st be submitted.	
(a) ☐ including changes required by the Notice of Draftspers	son's Patent Drawing Review (PTO	-948) attached
1)  hereto or 2)  to Paper No./Mail Date		
(b) including changes required by the attached Examiner' Paper No./Mail Date	s Amendment / Comment or in the 0	Office action of
Identifying indicia such as the application number (see 37 CFR 1 each sheet. Replacement sheet(s) should be labeled as such in t	.84(c)) should be written on the draw he header according to 37 CFR 1.121	ings in the front (not the back) of (d).
7. DEPOSIT OF and/or INFORMATION about the deposit attached Examiner's comment regarding REQUIREMENT	sit of BIOLOGICAL MATERIAL FOR THE DEPOSIT OF BIOLOGIC	must be submitted. Note the CAL MATERIAL. ਦ
Attachment(s)	5 Motion of Informat I	Patent Application (PTO-152)
1. Notice of References Cited (PTO-892)		Patent Application (PTO-152)
2. Notice of Draftperson's Patent Drawing Review (PTO-948)	6. ☐ Interview Summary Paper No./Mail Da	
3. ☑ Information Disclosure Statements (PTO-1449 or PTO/SB/0 Paper No./Mail Date	08), 7. Examiner's Amend	ment/Comment
4. Examiner's Comment Regarding Requirement for Deposit	<del>-</del>	ent of Reasons for Allowance
of Biological Material	9.  Other	

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## REASONS FOR ALLOWANCE

1. Claims 1, 3-7, 9-13, 15-19, 21-26, 28-34, 37, 39-40, 43, 46-47, 49-52 and 55-60 are allowed.

The following is an examiner's statement of reasons for allowance: the prior art of record does not anticipate nor render obvious to one ordinary skilled in the art a method of driving an IPS (in plane switching) reflective type active-matrix (TFTs) liquid crystal display device comprising a combination of various elements as claimed, more specifically, at least the followings: an interlayer insulating film provided over the thin film transistor, the interlayer insulating film being a multilayer film comprising silicon oxide and silicon nitride film.

Ohta (6108065) discloses an IPS LCD device comprising pixel and common electrodes formed on the same substrate, interlayer insulating film. However, Ohta fails to disclose 'a method of driving an IPS (in plane switching) reflective type active-matrix (TFTs) liquid crystal display device comprising a combination of various elements as claimed, more specifically, at least the followings: an interlayer insulating film provided over the thin film transistor, the interlayer insulating film being a multilayer film comprising silicon oxide and silicon nitride film'.

Applicant has also filed a terminal disclaimer to overcome the obviousness double patenting rejection.

Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

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## **CONTACT INFORMATION**

2. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Toan Ton whose telephone number is (571) 272-2303.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

March 3, 2005

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